

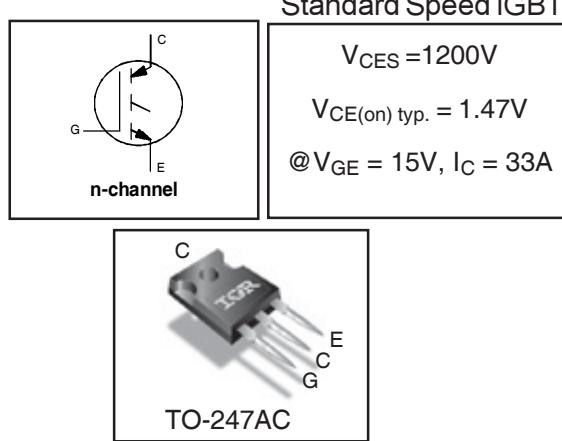
INSULATED GATE BIPOLAR TRANSISTOR

**Features**

- Standard: Optimized for minimum saturation voltage and low operating frequencies (< 1kHz)
- Generation 4 IGBT design provides tighter parameter distribution and higher efficiency
- Industry standard TO-247AC package
- Lead-Free
- Automotive Qualified \*

**Benefits**

- Generation 4 IGBT's offer highest efficiency available
- IGBT's optimized for specified application conditions



**Ordering Information**

Base part number	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRG4PH50S	TO-247AC	Tube	25	AUIRG4PH50S

**Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature ( $T_A$ ) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
$V_{CES}$	Collector-to-Emitter Voltage	1200	V
$I_C @ T_C = 25^\circ C$	Continuous Collector Current	57	A
$I_C @ T_C = 100^\circ C$	Continuous Collector Current	33	
$I_{CM}$	Pulsed Collector Current①	114	
$I_{LM}$	Clamped Inductive Load Current ②	114	V
$V_{GE}$	Gate-to-Emitter Voltage	$\pm 20$	
	Transient Gate-to-Emitter Voltage	$\pm 30$	
$E_{ARV}$	Reverse Voltage Avalanche Energy ③	270	mJ
$P_D @ T_C = 25^\circ$	Maximum Power Dissipation	200	W
$P_D @ T_C = 100^\circ$	Maximum Power Dissipation	80	
$T_J$ $T_{STG}$	Operating Junction and Storage Temperature Range	-55 to + 150	
	Soldering Temperature, for 10 sec.	300 (0.063 in. (1.6mm) from case)	°C
	Mounting Torque, 6-32 or M3 Screw.	10 lbf-in (1.1 N·m)	

**Thermal Resistance**

	Parameter	Min.	Typ.	Max.	Units
$R_{JC}$	Junction-to-Case	—	—	0.64	°C/W
$R_{CS}$	Case-to-Sink, Flat, Greased Surface	—	0.24	—	
$R_{QA}$	Junction-to-Ambient, typical socket mount	—	—	40	
Wt	Weight	—	6.0(0.21)	—	g (oz)

\*Qualification standards can be found at <http://www.irf.com/>

Dynamic Electrical Characteristics @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)

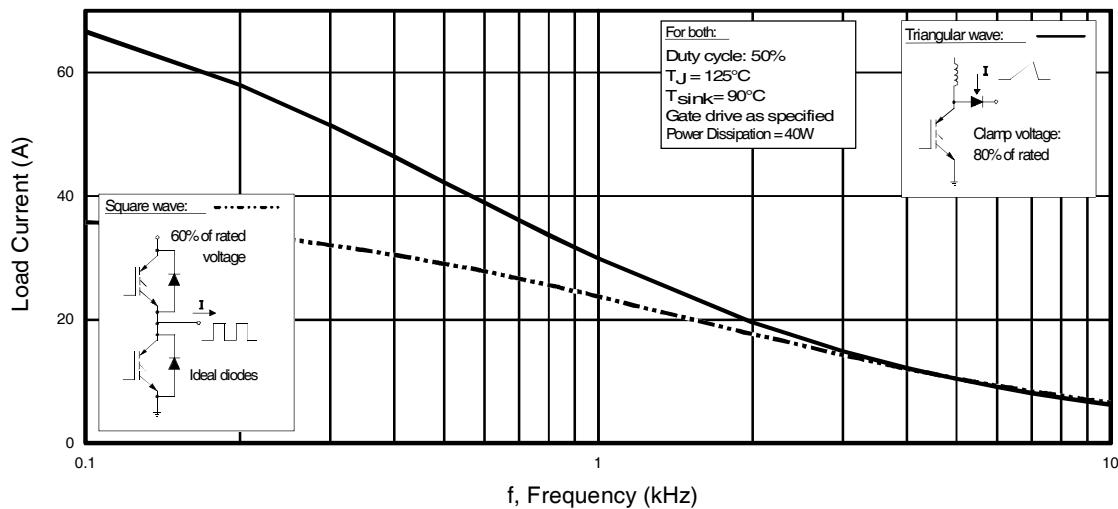
	Parameter	Min.	Typ.	Max.	Units	Conditions
$V_{(BR)CES}$	Collector-to-Emitter Breakdown Voltage	1200	—	—	V	$V_{GE} = 0\text{V}$ , $I_C = 250\mu\text{A}$
$V_{(BR)ECS}$	Emitter-to-Collector Breakdown Voltage ④	18	—	—	V	$V_{GE} = 0\text{V}$ , $I_C = 1.0\text{ A}$
$\Delta V_{(BR)CES}/\Delta T_J$	Temperature Coeff. of Breakdown Voltage	—	1.22	—	V/ $^\circ\text{C}$	$V_{GE} = 0\text{V}$ , $I_C = 2.0\text{ mA}$
$V_{CE(\text{ON})}$	Collector-to-Emitter Saturation Voltage	—	1.47	1.7	V	$I_C = 33\text{A}$ $V_{GE} = 15\text{V}$
		—	1.75	—		$I_C = 57\text{A}$ See Fig.2, 5
		—	1.55	—		$I_C = 33\text{A}$ , $T_J = 150^\circ\text{C}$
		—	—	—		$V_{CE} = V_{GE}$ , $I_C = 250\mu\text{A}$
$DV_{GE(\text{th})}/DT_J$	Temperature Coeff. of Threshold Voltage	—	-11	—	mV/ $^\circ\text{C}$	$V_{CE} = V_{GE}$ , $I_C = 250\mu\text{A}$
$g_{fe}$	Forward Transconductance ⑤	27	40	—	S	$V_{CE} = 100\text{V}$ , $I_C = 33\text{A}$
$I_{CES}$	Zero Gate Voltage Collector Current	—	—	250	$\mu\text{A}$	$V_{GE} = 0\text{V}$ , $V_{CE} = 1200\text{V}$
		—	—	2.0		$V_{GE} = 0\text{V}$ , $V_{CE} = 10\text{V}$ , $T_J = 25^\circ\text{C}$
		—	—	1000		$V_{GE} = 0\text{V}$ , $V_{CE} = 1200\text{V}$ , $T_J = 150^\circ\text{C}$
$I_{GES}$	Gate-to-Emitter Leakage Current	—	—	$\pm 100$	nA	$V_{GE} = \pm 20\text{V}$

Static or Switching Electrical Characteristics @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)

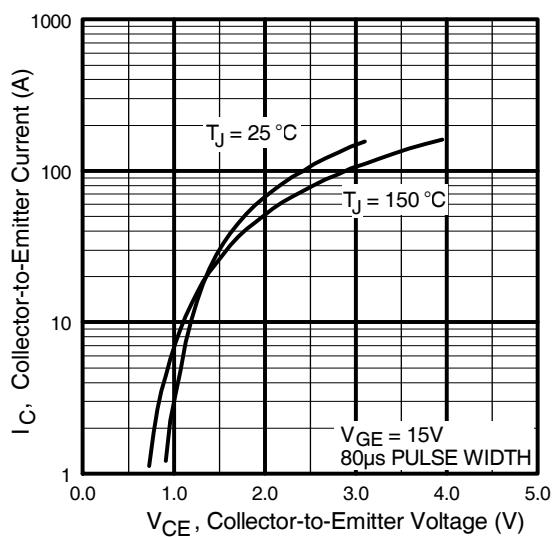
	Parameter	Min.	Typ.	Max.	Units	Conditions
$Q_g$	Total Gate Charge (turn-on)	—	167	251	nC	$I_C = 33\text{A}$
$Q_{ge}$	Gate - Emitter Charge (turn-on)	—	25	38		$V_{CC} = 400\text{V}$ See Fig. 8
$Q_{gc}$	Gate - Collector Charge (turn-on)	—	55	83		$V_{GE} = 15\text{V}$
$t_{d(on)}$	Turn-On Delay Time	—	32	—	ns	$T_J = 25^\circ\text{C}$ $I_C = 33\text{A}$ , $V_{CC} = 960\text{V}$ $V_{GE} = 15\text{V}$ , $R_G = 5.0\Omega$
$t_r$	Rise Time	—	29	—		
$t_{d(off)}$	Turn-Off Delay Time	—	845	1268		
$t_f$	Fall Time	—	425	638		
$E_{on}$	Turn-On Switching Loss	—	1.80	—	mJ	Energy losses include "tail" See Fig. 9, 10, 14
$E_{off}$	Turn-Off Switching Loss	—	19.6	—		
$E_{ts}$	Total Switching Loss	—	21.4	44		
$t_{d(on)}$	Turn-On Delay Time	—	32	—	ns	$T_J = 150^\circ\text{C}$ , $I_C = 33\text{A}$ , $V_{CC} = 960\text{V}$ $V_{GE} = 15\text{V}$ , $R_G = 5.0\Omega$
$t_r$	Rise Time	—	30	—		
$t_{d(off)}$	Turn-Off Delay Time	—	1170	—		
$t_f$	Fall Time	—	1000	—		
$E_{ts}$	Total Switching Loss	—	37	—	mJ	Energy losses include "tail" See Fig. 10, 11, 14
$L_E$	Internal Emitter Inductance	—	13	—	nH	Measured 5mm from package
$C_{ies}$	Input Capacitance	—	3600	—	pF	$V_{GE} = 0\text{V}$
$C_{oes}$	Output Capacitance	—	160	—		$V_{CC} = 30\text{V}$ See Fig. 7
$C_{res}$	Reverse Transfer Capacitance	—	30	—		$f = 1.0\text{MHz}$

## Notes:

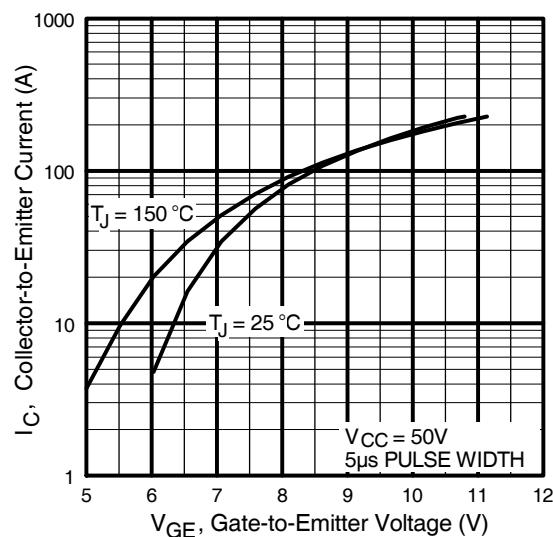
- ① Repetitive rating;  $V_{GE} = 20\text{V}$ , pulse width limited by max. junction temperature. ( See fig. 13b )
- ②  $V_{CC} = 80\%(V_{CES})$ ,  $V_{GE} = 20\text{V}$ ,  $L = 10\mu\text{H}$ ,  $R_G = 5.0\Omega$ , (See fig. 13a)
- ③ Repetitive rating; pulse width limited by maximum junction temperature.
- ④ Pulse width  $\leq 80\mu\text{s}$ ; duty factor  $\leq 0.1\%$ .
- ⑤ Pulse width  $5.0\mu\text{s}$ , single shot.



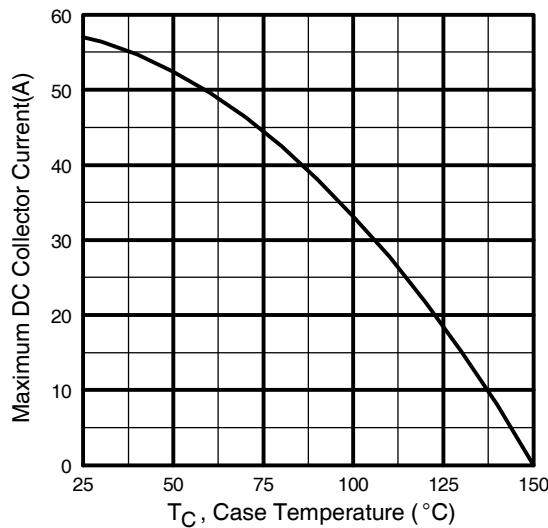
**Fig. 1** - Typical Load Current vs. Frequency  
(Load Current =  $I_{RMS}$  of fundamental)



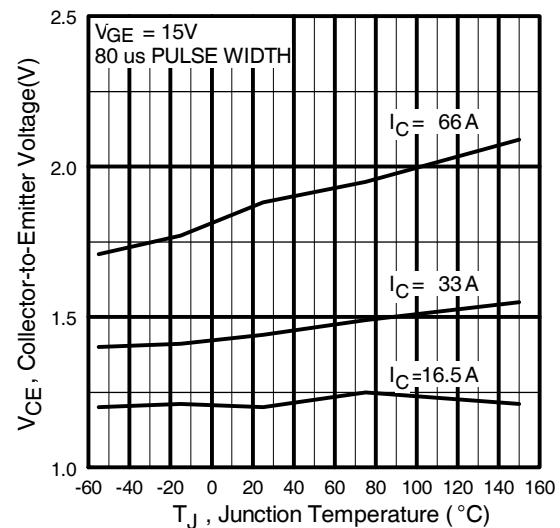
**Fig. 2** - Typical Output Characteristics



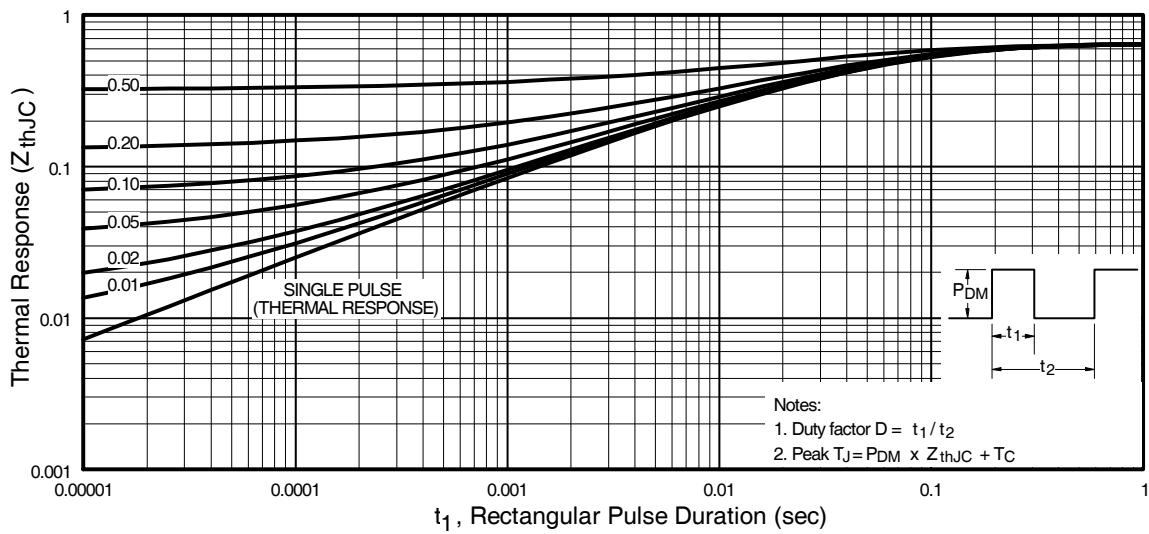
**Fig. 3** - Typical Transfer Characteristics



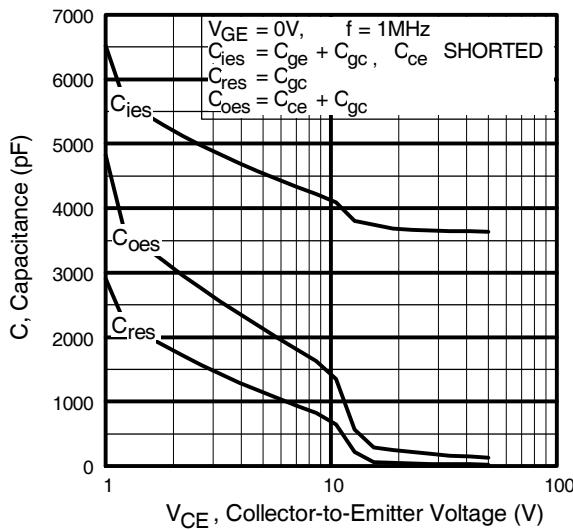
**Fig. 4** - Maximum Collector Current vs. Case Temperature



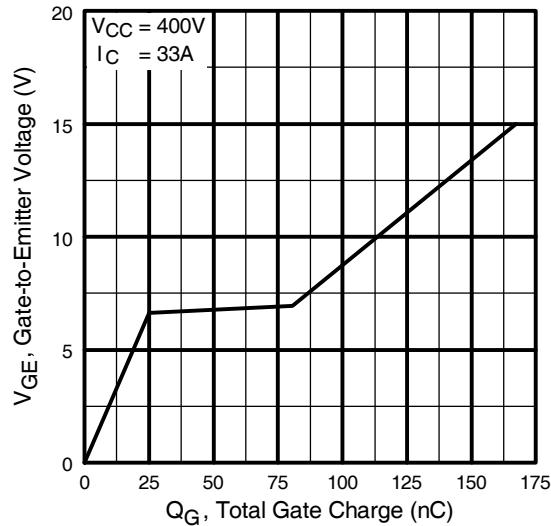
**Fig. 5** - Typical Collector-to-Emitter Voltage vs. Junction Temperature



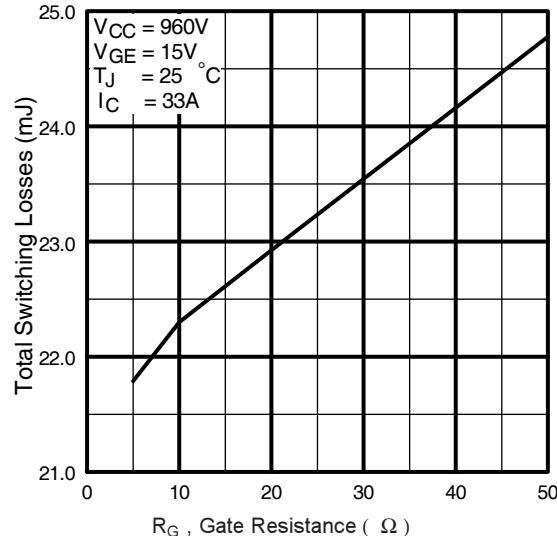
**Fig. 6** - Maximum Effective Transient Thermal Impedance, Junction-to-Case



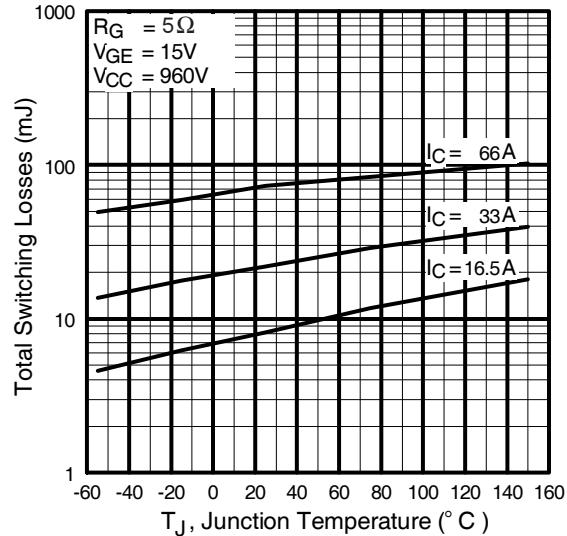
**Fig. 7** - Typical Capacitance vs.  
Collector-to-Emitter Voltage



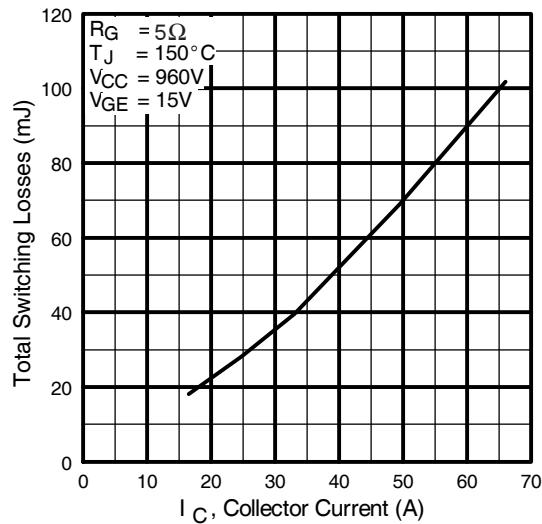
**Fig. 8** - Typical Gate Charge vs.  
Gate-to-Emitter Voltage



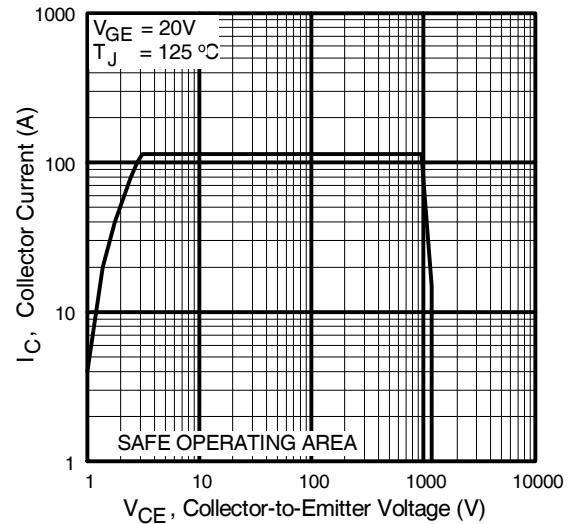
**Fig. 9** - Typical Switching Losses vs. Gate  
Resistance



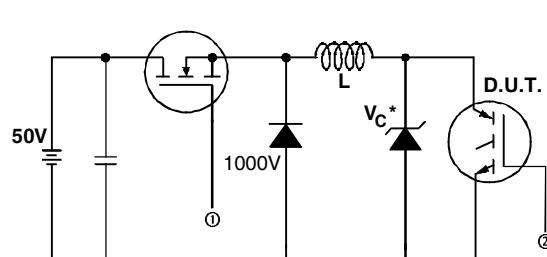
**Fig. 10** - Typical Switching Losses vs.  
Junction Temperature



**Fig. 11** - Typical Switching Losses vs.  
Collector-to-Emitter Current

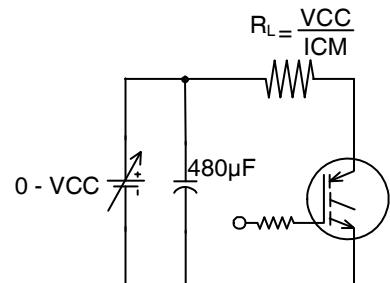


**Fig. 12** - Reverse Bias SOA



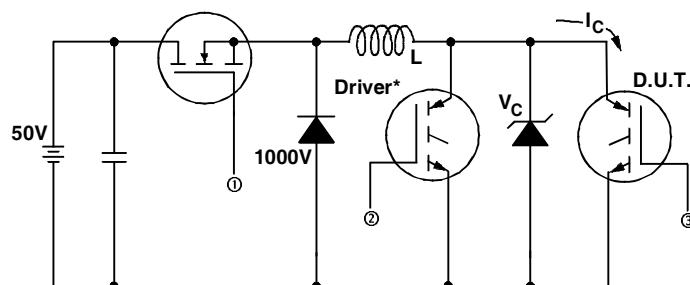
\* Driver same type as D.U.T.;  $V_c = 80\%$  of  $V_{ce(\max)}$   
 \* Note: Due to the 50V power supply, pulse width and inductor will increase to obtain rated  $I_d$ .

**Fig. 13a** - Clamped Inductive Load Test Circuit



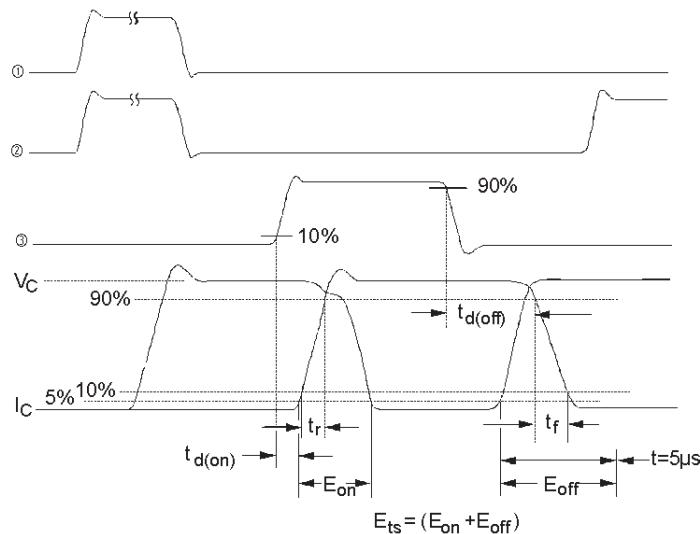
Pulsed Collector Current Test Circuit

**Fig. 13b** - Pulsed Collector Current Test Circuit



**Fig. 14a** - Switching Loss Test Circuit

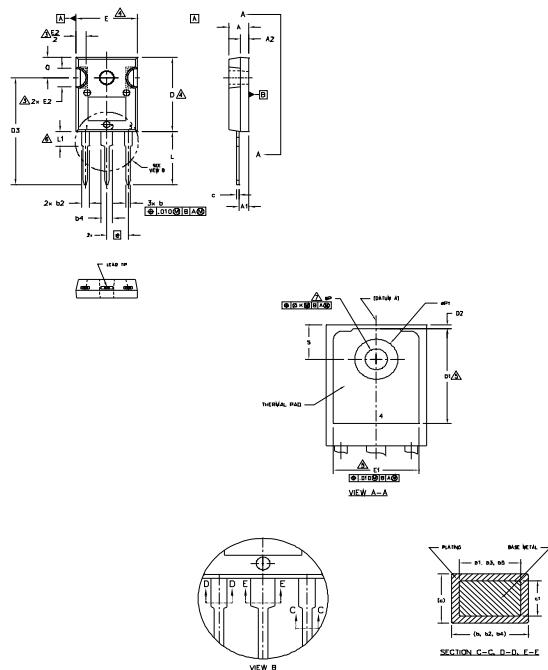
\* Driver same type as D.U.T.,  $V_C = \text{---V}$



**Fig. 14b** - Switching Loss Waveforms

## TO-247AC Package Outline

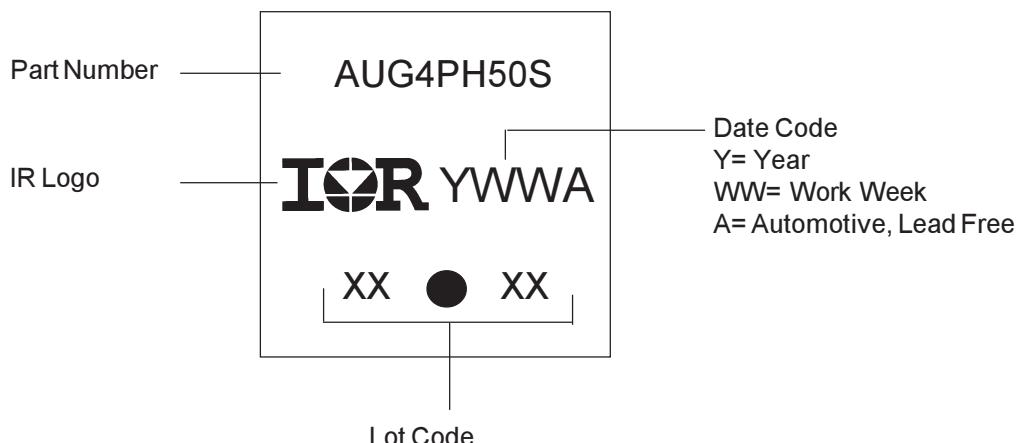
Dimensions are shown in millimeters (inches)



SYMBOL	DIMENSIONS				NOTES	
	INCHES		MILLIMETERS			
	MIN.	MAX.	MIN.	MAX.		
A	.183	.209	4.65	5.31		
A1	.087	.109	2.22	2.59		
A2	.059	.079	1.50	2.49		
b	.039	.055	0.99	1.40		
b1	.039	.053	0.99	1.35		
b2	.066	.094	1.65	2.39		
b3	.066	.094	1.65	2.34		
b4	.102	.135	2.59	3.43		
b5	.102	.133	2.59	3.38		
c	.015	.035	0.38	0.89		
c1	.015	.033	0.38	0.84		
D	.776	.815	19.71	20.70	4	
D1	.515	—	13.08	—	5	
D2	.020	.053	0.51	1.35		
D3	1.122	1.161	28.50	29.50		
E	.602	.625	15.29	15.87		
E1	.530	—	13.46	—		
E2	.178	.216	4.52	5.49		
e	.215 BSC		5.46 BSC			
ek	.010		0.25			
L	.559	.634	14.20	16.10		
L1	.146	.169	3.71	4.29		
#P	.140	.144	3.56	3.66		
#P1	—	.291	—	7.39		
Q	.209	.224	5.31	5.69		
S	.217 BSC		5.51 BSC			

SPECIAL NOTE:

# TO-247AC Part Marking Information



**Note: For the most current drawing please refer to IR website at <http://www.irf.com/package/>**

**Qualification Information<sup>†</sup>**

<b>Qualification Level</b>	Automotive (per AEC-Q101) <sup>††</sup>	
	Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.	
<b>Moisture Sensitivity Level</b>	TO-247AC	N/A
<b>ESD</b>	Machine Model	Class M3 AEC-Q101-002
	Human Body Model	Class H2 AEC-Q101-001
	Charged Device Model	Class C4 AEC-Q101-005
<b>RoHS Compliant</b>	Yes	

<sup>†</sup> Qualification standards can be found at International Rectifier's web site: <http://www.irf.com/>

<sup>††</sup> Exceptions to AEC-Q101 requirements are noted in the qualification report.

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